

**2SJ562**

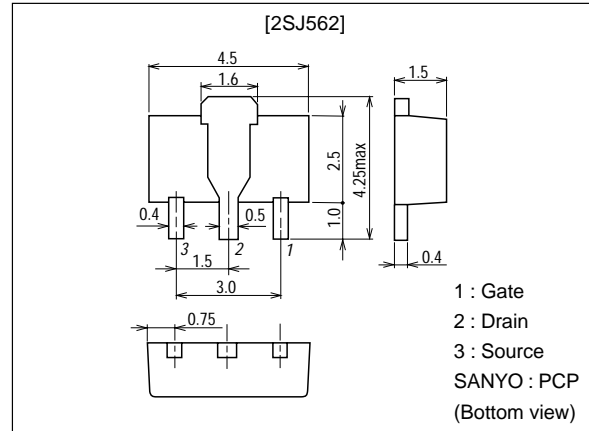
## Ultrahigh-Speed Switching Applications

### Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

### Package Dimensions

unit:mm  
2062A



### Specifications

#### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSS}$		-20	V
Gate-to-Source Voltage	$V_{GSS}$		$\pm 10$	V
Drain Current (DC)	$I_D$		-2	A
Drain Current (Pulse)	$I_{DP}$	$PW \leq 10\mu\text{s}$ , duty cycle $\leq 1\%$	-8	A
Allowable Power Dissipation	$P_D$	Mounted on a ceramic board (250mm <sup>2</sup> × 0.8mm)	1.5	W
		$T_c = 25^\circ\text{C}$	3.5	W
Channel Temperature	$T_{ch}$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

#### Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}$ , $V_{GS} = 0$	-20			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -20\text{V}$ , $V_{GS} = 0$			-10	$\mu\text{A}$
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 8\text{V}$ , $V_{DS} = 0$			$\pm 10$	$\mu\text{A}$
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{V}$ , $I_D = -1\text{mA}$	-0.4		-1.4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10\text{V}$ , $I_D = -1\text{A}$	1.8	2.6		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -1\text{A}$ , $V_{GS} = -4\text{V}$		245	315	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D = -200\text{mA}$ , $V_{GS} = -2.5\text{V}$		340	480	$\text{m}\Omega$

Marking : JN

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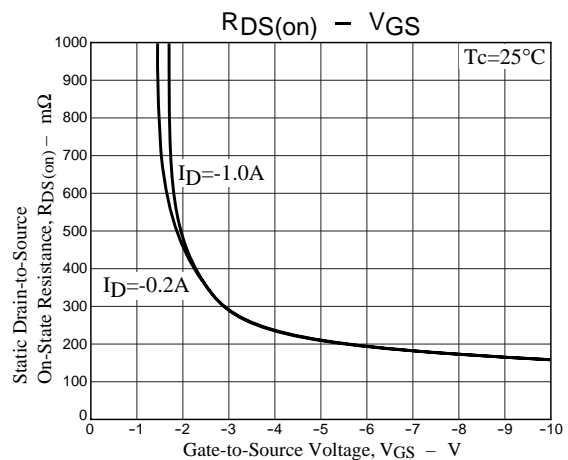
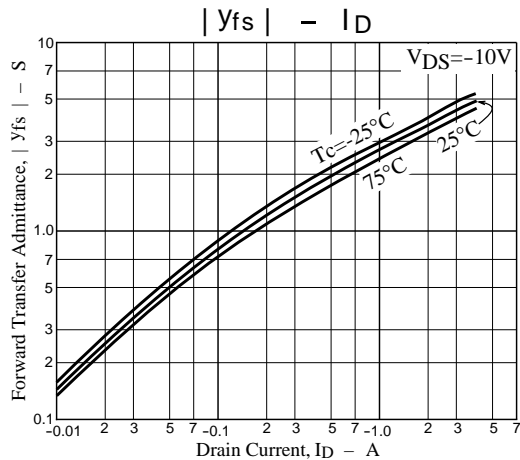
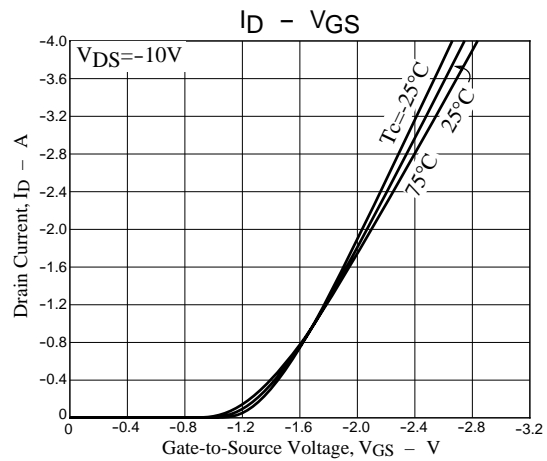
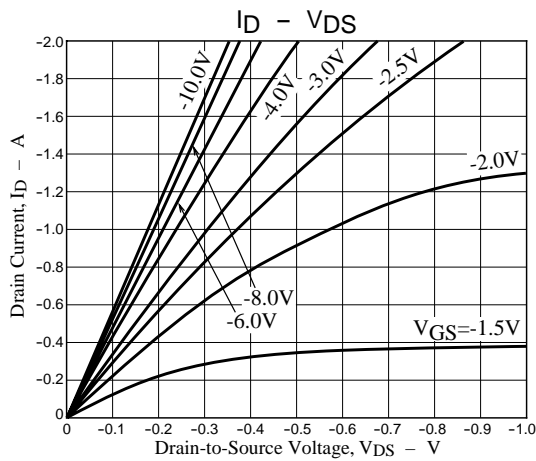
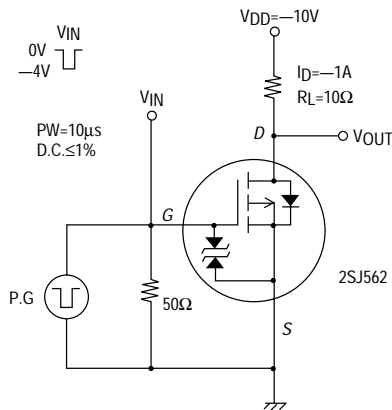
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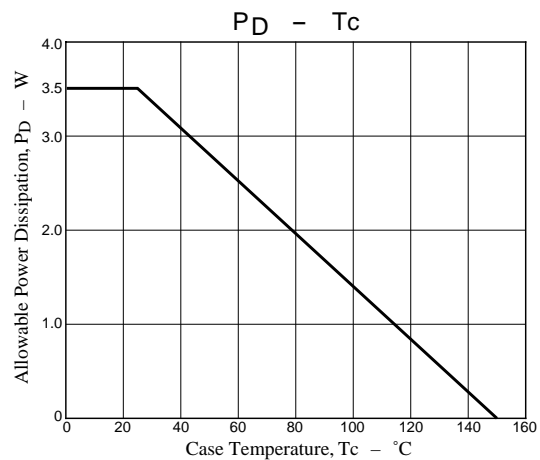
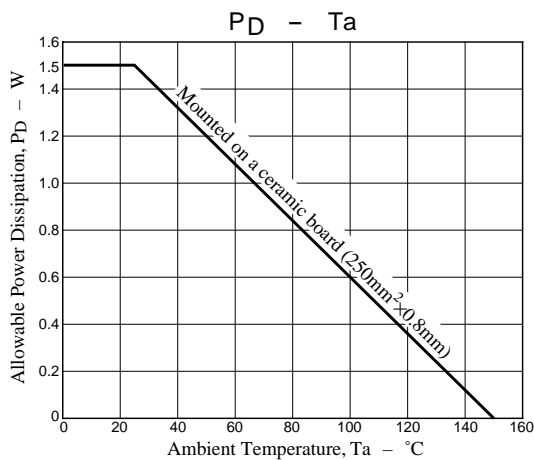
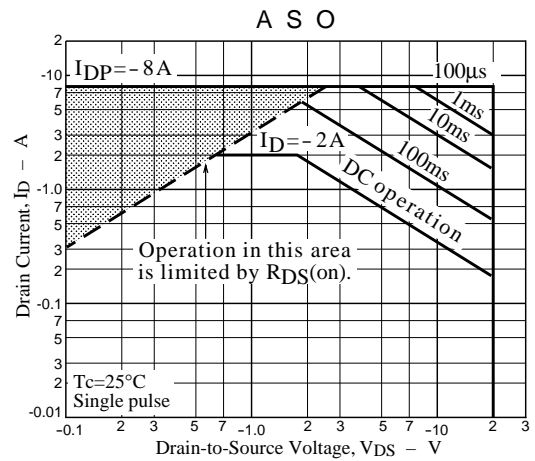
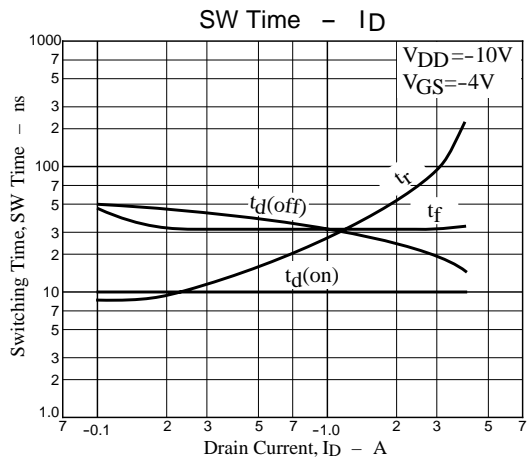
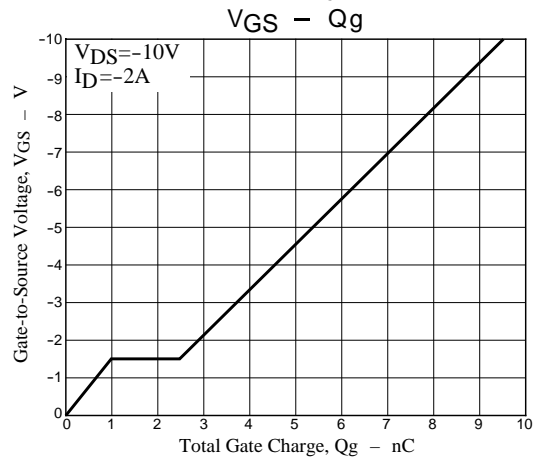
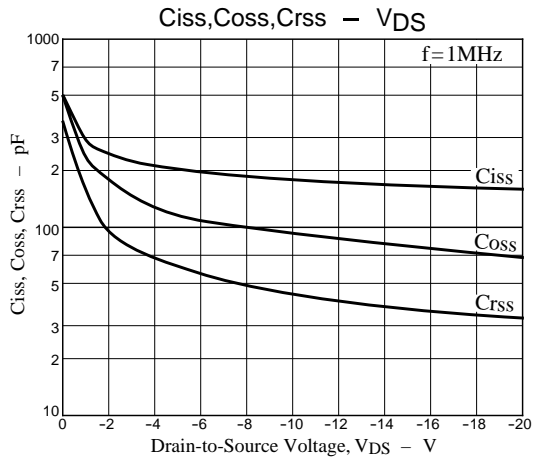
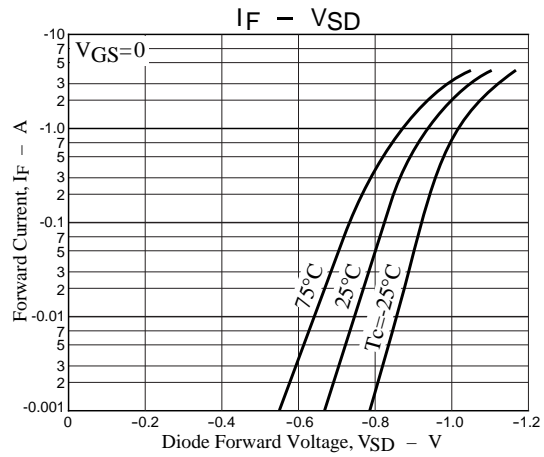
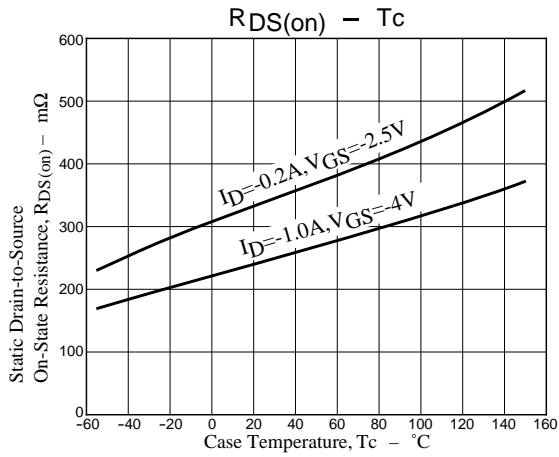
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	$C_{iss}$	$V_{DS}=-10V, f=1MHz$		180		pF
Output Capacitance	$C_{oss}$	$V_{DS}=-10V, f=1MHz$		90		pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{DS}=-10V, f=1MHz$		43		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		10		ns
Rise Time	$t_r$	See specified Test Circuit		28		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		32		ns
Fall Time	$t_f$	See specified Test Circuit		32		ns
Total Gate Charge	$Q_g$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-2A$		9.5		nC
Gate-to-Source Charge	$Q_{gs}$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-2A$		1		nC
Gate-to-Drain "Miller" Charge	$Q_{gd}$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-2A$		1.5		nC
Diode Forward Voltage	$V_{SD}$	$I_S=-2A, V_{GS}=0$	-1.0	-1.5		V

## Switching Time Test Circuit



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